

RD74LVC125B

Quad. Bus Buffer Gates with 3-state Outputs

REJ03D0498-0200 Rev.2.00 Dec. 10, 2004

Description

The RD74LVC125B has four bus buffer gates in a 14 pin package. The device requires the three state control input $\overline{\text{OE}}$ to be taken high to put the output into the high impedance condition. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_{OUT} (Max.) = 5.5 V (@ V_{CC} = 0 V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$
 - $\pm 8 \text{ mA} (@V_{CC} = 2.3 \text{ V})$
 - $\pm 12 \text{ mA } (@V_{CC} = 2.7 \text{ V})$
 - ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC125BFPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
RD74LVC125BTELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Function Table

Inp		
ŌĒ	Α	Outputs Y
Н	X	Z
L	L	L
L	Н	Н

H: High level

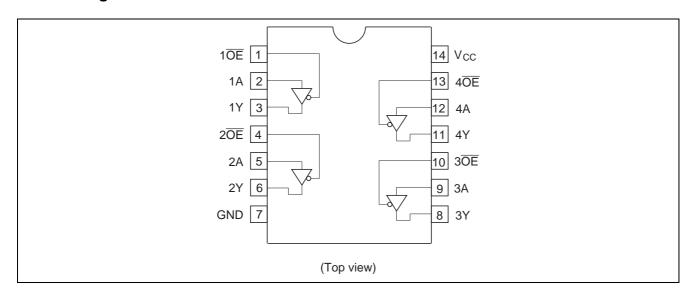
L: Low level

X: Immaterial

Z: High impedance

Pin Arrangement

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Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	–0.5 to 7.0	V	
Input diode current	I _{IK}	– 50	mA	$V_1 = -0.5 \text{ V}$
Input voltage	VI	–0.5 to 7.0	V	
Output diode current	I _{OK}	-50	mA	$V_0 = -0.5 \text{ V}$
		50		$V_O = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	–0.5 to V _{CC} +0.5	V	Output "H" or "L"
		–0.5 to 7.0		Output "Z" or V _{CC} : OFF
Output current	Io	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	±100	mA	
Storage temperature	Tstg	–65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.





Recommended Operating Conditions

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Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	1.5 to 5.5	V	Data hold
		1.65 to 5.5		At operation
Input / output voltage	Vı	0 to 5.5	V	
	Vo	0 to V _{CC}	V	Output "H" or "L"
		0 to 5.5		Output "Z" or V _{CC} : OFF
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	-4	mA	V _{CC} = 1.65 V
		-8		$V_{CC} = 2.3 \text{ V}$
		-12		$V_{CC} = 2.7 \text{ V}$
		-24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
	I _{OL}	4	mA	V _{CC} = 1.65 V
		8		$V_{CC} = 2.3 \text{ V}$
		12		$V_{CC} = 2.7 \text{ V}$
		24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
Input rise / fall time *1	t _r , t _f	20	ns/V	V _{CC} = 1.65 V to 2.7 V
		10		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

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			Ta = -40 to 85°C			
Item	Symbol	V _{CC} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.65	_	V	
		2.3 to 2.7	1.7	_		
		2.7 to 3.6	2.0	_		
		4.5 to 5.5	V _{CC} ×0.7	_		
	V _{IL}	1.65 to 1.95	_	V _{CC} ×0.35	V	
		2.3 to 2.7	_	0.7		
		2.7 to 3.6	_	0.8		
		4.5 to 5.5	_	V _{CC} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} -0.2	_	V	I _{OH} = -100 μA
		1.65	1.2	_		$I_{OH} = -4 \text{ mA}$
		2.3	1.7	_		$I_{OH} = -8 \text{ mA}$
		2.7	2.2	_		I _{OH} = -12 mA
		3.0	2.4	_		
		3.0	2.2	_		I _{OH} = -24 mA
		4.5	3.8	_		
	V _{OL}	1.65 to 5.5	_	0.2	V	I _{OL} = 100 μA
		1.65	_	0.45		I _{OL} = 4 mA
		2.3		0.7		I _{OL} = 8 mA
		2.7	_	0.4		I _{OL} = 12 mA
		3.0	_	0.55		I _{OL} = 24 mA
		4.5	_	0.55		
Input current	I _{IN}	0 to 5.5	_	±5.0	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Output leak current	I _{OFF}	0	_	±5.0	μΑ	$V_{IN} / V_{OUT} = 5.5 V$
Off state output current	loz	2.7 to 5.5	_	±5.0	μΑ	V _{IN} = V _{CC} or GND,
						V _{OUT} = 5.5 V or GND
Quiescent supply current	I _{CC}	2.7 to 3.6	_	±5.0	μΑ	V _{IN} = 3.6 V to 5.5 V
		2.7 to 5.5	_	5.0		V _{IN} = V _{CC} or GND
	Δl _{CC}	2.7 to 3.6	_	500	μΑ	V_{IN} = one input at (V_{CC} –0.6) V, other inputs at V_{CC} or GND

Switching Characteristics

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			Ta = -40 to 85°C				From	То
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	1.8±0.15	1.0	_	12.3	ns	Α	Υ
	t _{PHL}	2.5±0.2	1.0	_	6.3			
		2.7	1.0	_	5.5			
		3.3±0.3	1.0	_	4.8			
		5.0±0.5	1.0	_	3.8			
Output enable time	t _{ZH}	1.8±0.15	1.0	_	14.3	ns	ŌE	Υ
	t_{ZL}	2.5±0.2	1.0	_	7.4			
		2.7	1.0	_	6.6			
		3.3±0.3	1.0	_	5.4			
		5.0±0.5	1.0	_	4.4			
Output disable time	t _{HZ}	1.8±0.15	1.0	_	11.1	ns	ŌĒ	Υ
	t_{LZ}	2.5±0.2	1.0	_	5.6			
		2.7	1.0	_	5.0			
		3.3±0.3	1.0	_	4.6			
		5.0±0.5	1.0	_	3.6			
Between output pins skew *	t _{OSLH}	1.8±0.15	_	_	_	ns		
	t _{OSHL}	2.5±0.2	_	_	_			
		2.7	_	_	_			
		3.3±0.3	_	_	1.0			
		5.0±0.5	_	_	1.0			
Input capacitance	C _{IN}	3.3	_	4.0	_	pF		
Output capacitance	Co	3.3	_	7.0	_	pF		

Note: 1. This parameter is characterized but not tested.

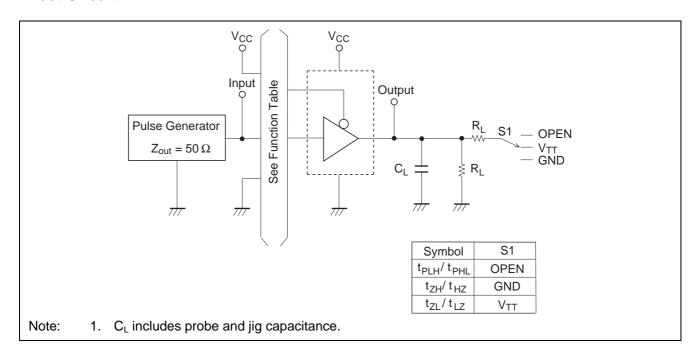
 $tos_{LH} = |t_{PLHm} - t_{PLHn}|, tos_{HL} = |t_{PHLm} - t_{PHLn}|$

Operating Characteristics

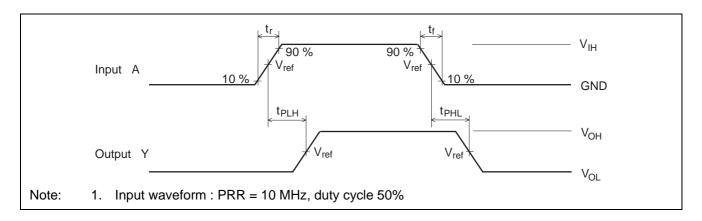
 $Ta = 25^{\circ}C$

Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test conditions
Power dissipation	C_{PD}	1.8	_	21	_	pF	f = 10 MHz
capacitance		2.5	_	22	_		
		3.3	_	23	_		
		5.0	_	27	_		

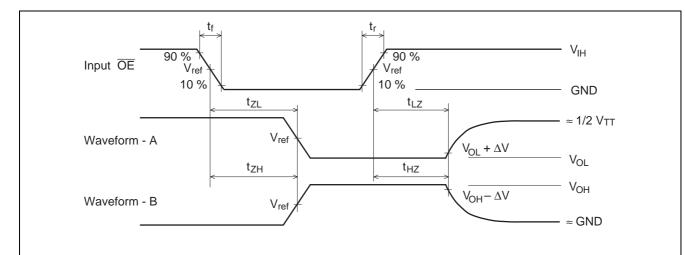
Test Circuit www.DataSheet4U.com



Waveforms – 1 www.DataSheet4U.com



Waveforms - 2

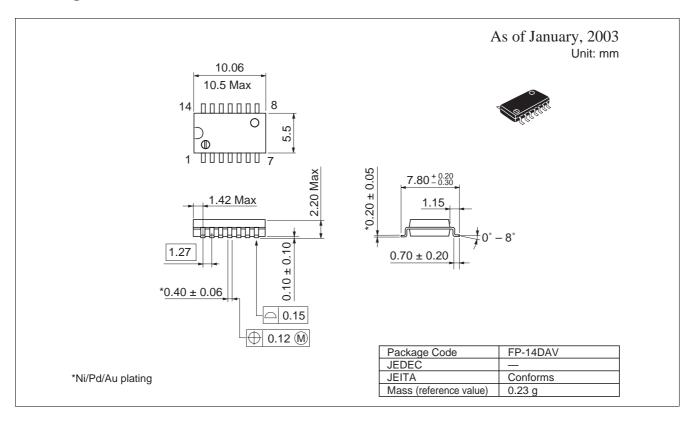


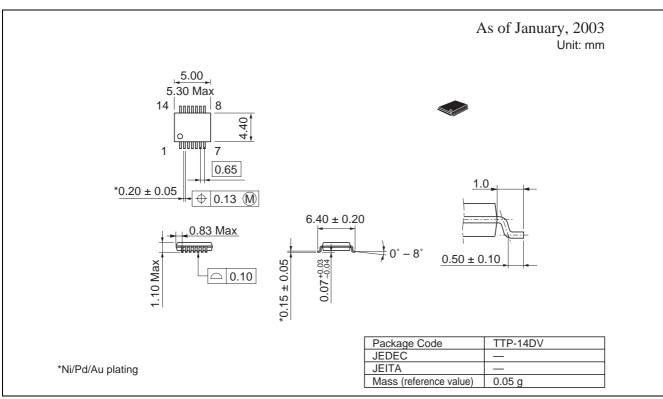
	INPUTS						
Vcc (V)	Vı	tr/tf	Vref	VTT	CL	RL	ΔV
Vcc = 1.8±0.15 V	Vcc	≤ 2 ns	1/2 Vcc	2× Vcc	30 pF	1.0 kΩ	0.15 V
Vcc = 2.5±0.2 V	Vcc	≤ 2 ns	1/2 Vcc	2× Vcc	30 pF	500 Ω	0.15 V
Vcc = 2.7 V	2.7 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
Vcc = 3.3±0.3 V	2.7 V	≤ 2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
Vcc = 5.0±0.5 V	Vcc	≤ 2.5 ns	1/2 Vcc	2× Vcc	50 pF	500 Ω	0.3 V

Notes:

- 1. Input waveform : PRR = 10 MHz, duty cycle 50%
- 2. Waveform A shows input conditions such that the output is "L" level when enable by the output control.
- 3. Waveform B shows input conditions such that the output is "H" level when enable by the output control.

Package Dimensions





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